



# **Dual P-Channel 20-V (D-S) MOSFET**

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
- 20	$0.017$ at $V_{GS} = -4.5 \text{ V}$	- 12		
	0.020 at V <sub>GS</sub> = - 2.5 V	- 11		
	0.024 at V <sub>GS</sub> = - 1.8 V	- 10.1		

# PowerPAK SO-8 6.15 mm 5.15 mm 2 3 4 Bottom View

Ordering Information: Si7983DP-T1-E3 (Lead (Pb)-free)

Si7983DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### **FEATURES**

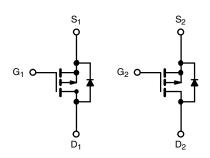
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET<sup>®</sup> Power MOSFET
- New Low Thermal Resistance PowerPAK<sup>®</sup>
   Package with Low 1.07 mm Profile



ROHS
COMPLIANT
HALOGEN
FREE

#### **APPLICATIONS**

· Load Switch



P-Channel MOSFET

P-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	$T_A = 25$ °C, unles	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		$V_{DS}$	- 20		V	
Gate-Source Voltage		$V_{GS}$	± 8			
Continuous Drain Current (T <sub>.I</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 12	- 7.7		
Continuous Drain Current (1,j = 150 °C)	T <sub>A</sub> = 70 °C		- 9.6	- 6.2	Α	
Pulsed Drain Current		I <sub>DM</sub>	- 30		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 2.9	- 1.2		
Maximum Dawar Dissinations	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.5	1.4	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		2.2	0.9		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature)b, c			2			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 s	R <sub>thJA</sub>	26	35	
Maximum Junction-to-Ambient	Steady State		60	85	°C/W
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	2.2	2.7	

#### Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<a href="http://www.vishay.com/ppg?73257">http://www.vishay.com/ppg?73257</a>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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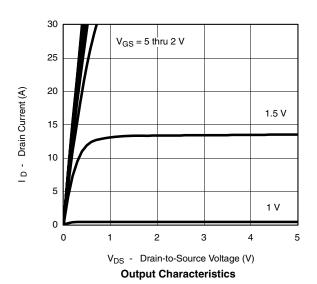
Parameter	Symbol	Test Conditions Min. 1		Тур.	Max.	Unit	
Static	-						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -600 \mu A$	- 0.40		- 1	V	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 8 V			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 20 V, V <sub>GS</sub> = 0 V	- 1		- 1		
		$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 5	- μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 30			Α	
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 12 A		0.014	0.017	Ω	
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 11 A		0.016	0.020		
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 4.1 A		0.020	0.024		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 12 A		41		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 2.9 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$			49	74		
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ = - 10 V, $V_{GS}$ = - 4.5 V, $I_D$ = - 12 A		7.2		nC	
Gate-Drain Charge	$Q_{gd}$			12.1			
Gate Resistance	$R_g$	f = 1 MHz		8		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			35	55		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 10 V, $R_L$ = 10 $\Omega$		60	90	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 4.5 V, $\text{R}_g$ = 6 $\Omega$		390	585		
Fall Time	t <sub>f</sub>			190	285		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 2.9 A, dl/dt = 100 A/μs		106	160		

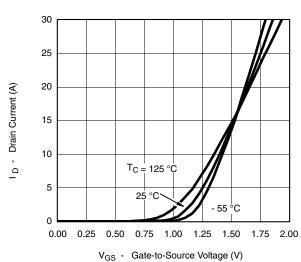
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



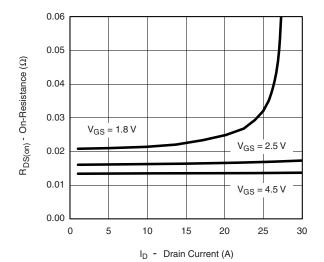




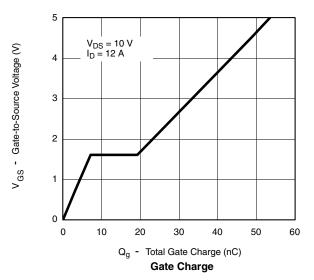


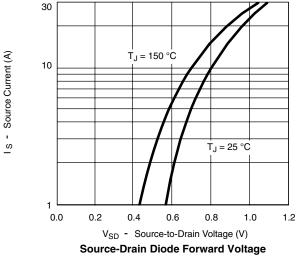


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On-Resistance vs. Drain Current



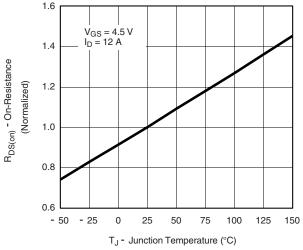


6000 5000  $\mathsf{C}_{\mathsf{iss}}$ C - Capacitance (pF) 4000 3000 2000 Coss 1000  $C_{\text{rss}}$ 0 8 20 0 12 16

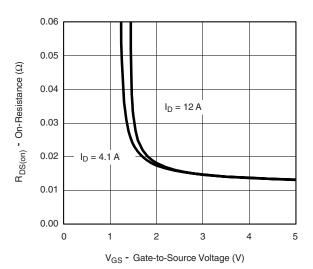
V<sub>DS</sub> - Drain-to-Source Voltage (V)

Capacitance





On-Resistance vs. Junction Temperature

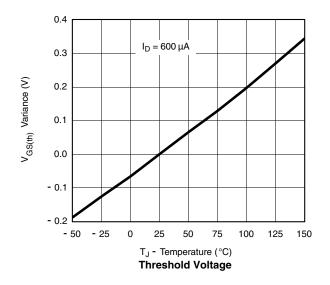


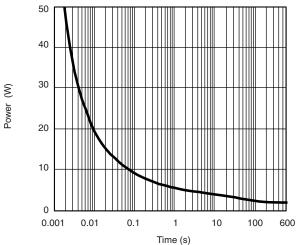
On-Resistance vs. Gate-to-Source Voltage

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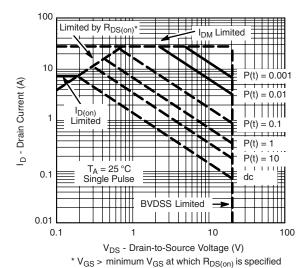
# VISHAY

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

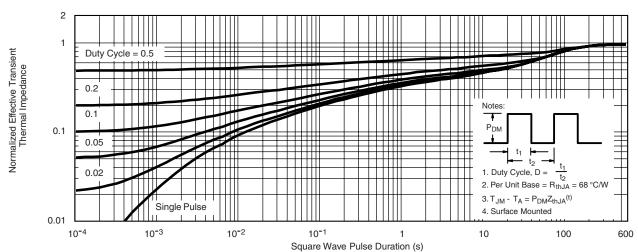




Single Pulse Power, Junction-to-Ambient



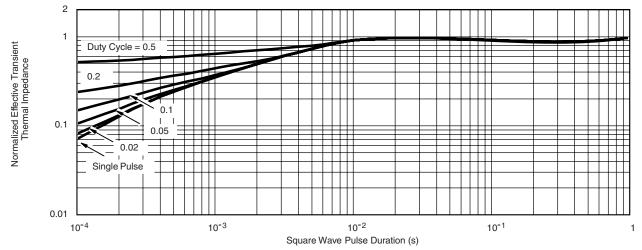
#### Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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